

Features

- Rail-to-rail input and output
- Wide supply voltage: 4 V - 16 V
- Gain bandwidth product: 10 MHz typ at 16 V
- Low power consumption: 2.8 mA typ per amplifier at 16 V
- Unity gain stable
- Low input bias current: 10 pA typ
- High tolerance to ESD: 4 kV HBM
- Extended temperature range:
-40 °C to +125 °C
- Automotive qualification

Related products

- See the TSX5 series for low power features
- See the TSX6 series for micro power features
- See the TSX929 series for higher speeds
- See the TSV9 series for lower voltages

Applications

- Communications
- Process control
- Test equipment

勝特力材料 886-3-5753170
胜特力电子(上海) 86-21-34970699
胜特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

Description

The TSX92x single and dual operational amplifiers (op-amps) offer excellent AC characteristics such as 10 MHz gain bandwidth, 17 V/μs slew rate, and 0.0003 % THD+N. These features make the TSX92x family particularly well-adapted for communications, I/V amplifiers for ADCs, and active filtering applications.

Their rail-to-rail input and output capability, while operating on a wide supply voltage range of 4 V to 16 V, allows these devices to be used in a wide range of applications. Automotive qualification is available as these devices can be used in this market segment.

Shutdown mode is available on the single (TSX920) and dual (TSX923) versions enabling an important current consumption reduction while this function is active.

The TSX92x family is available in SMD packages featuring a high level of integration. The DFN8 package, used in the TSX922, with a typical size of 2x2 mm and a maximum height of 0.8 mm offers even greater package size reduction.

Table 1. Device summary

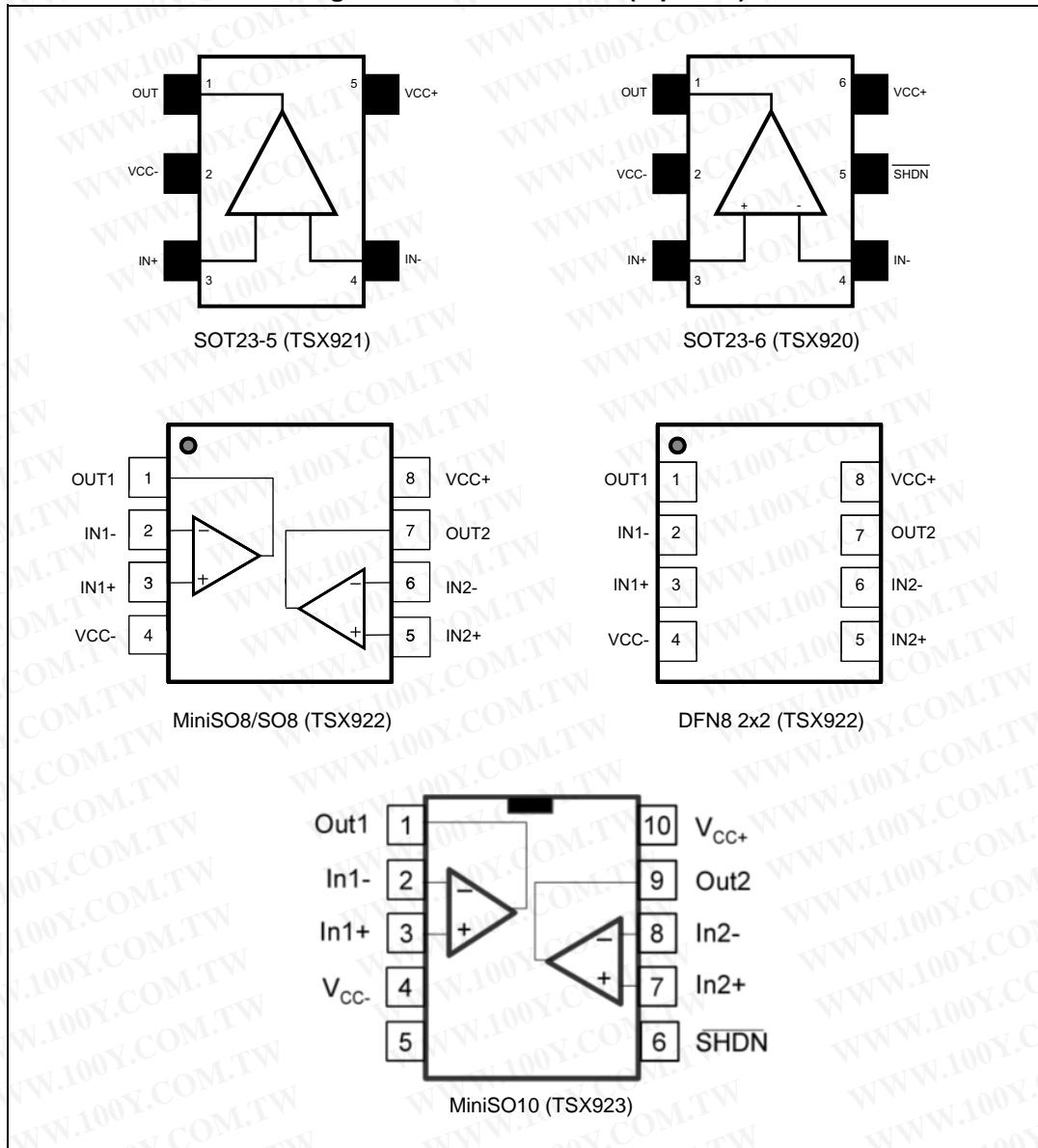
Op-amp version	With shutdown mode	Without shutdown mode
Single	TSX920	TSX921
Dual	TSX923	TSX922

Contents

1	Package pin connections	3
2	Absolute maximum ratings and operating conditions	4
3	Electrical characteristics	5
4	Application information	17
4.1	Operating voltages	17
4.2	Rail-to-rail input	17
4.3	Input pin voltage range	17
4.4	Capacitive load	18
4.5	High side current sensing	19
4.6	High speed photodiode	20
5	Package information	21
5.1	SOT23-5 package mechanical data	22
5.2	SOT23-6 package mechanical data	23
5.3	MiniSO8 package information	24
5.4	SO8 package information	25
5.5	DFN8 2x2 package information	26
5.6	MiniSO10 package information	27
6	Ordering information	28
7	Revision history	28

1 Package pin connections

Figure 1. Pin connections (top view)



2**Absolute maximum ratings and operating conditions****Table 2. Absolute maximum ratings (AMR)**

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage ⁽¹⁾	18	V
V_{id}	Differential input voltage ⁽²⁾	$\pm V_{CC}$	mV
V_{in}	Input voltage	$V_{CC-} - 0.2$ to $V_{CC+} + 0.2$	V
I_{in}	Input current ⁽³⁾	10	mA
T_{stg}	Storage temperature	-65 to +150	°C
R_{thja}	Thermal resistance junction to ambient ⁽⁴⁾⁽⁵⁾ SOT23-5 SOT23-6 MiniSO8 SO8 DFN8 2x2 MiniSO10	250 240 190 125 57 113	°C/W
T_j	Maximum junction temperature	150	°C
ESD	HBM: human body model ⁽⁶⁾	4000	V
	MM: machine model ⁽⁷⁾	100	
	CDM: charged device model ⁽⁸⁾	1500	
	Latch-up immunity	200	mA

1. All voltage values, except the differential voltage are with respect to network ground terminal.
2. The differential voltage is the non-inverting input terminal with respect to the inverting input terminal.
3. Input current must be limited by a resistor in series with the inputs.
4. Short-circuits can cause excessive heating and destructive dissipation.
5. R_{th} are typical values.
6. According to JEDEC standard JESD22-A114F
7. According to JEDEC standard JESD22-A115A
8. According to ANSI/ESD STM5.3.1

Table 3. Operating conditions

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	4 to 16	V
V_{icm}	Common mode input voltage range	$V_{CC-} - 0.1$ to $V_{CC+} + 0.1$	
T_{oper}	Operating free air temperature range	-40 to +125	°C

3 Electrical characteristics

Table 4. Electrical characteristics at $V_{CC+} = +4.5$ V with $V_{CC-} = 0$ V, $V_{icm} = V_{CC}/2$, $T_{amb} = 25$ °C, and $R_L = 10$ kΩ connected to $V_{CC}/2$ (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{io}	Input offset voltage	$V_{icm} = 2$ V $T_{min} < T_{op} < T_{max}$			4 5	mV
$\Delta V_{io}/\Delta T$	Input offset voltage drift			2	10	µV/°C
I_{ib}	Input bias current	$V_{out} = V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		10	100 200	pA
I_{io}	Input offset current	$V_{out} = V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		10	100 200	
R_{IN}	Input resistance			1		TΩ
C_{IN}	Input capacitance			8		pF
CMRR	Common mode rejection ratio 20 log ($\Delta V_{ic}/\Delta V_{io}$)	$V_{icm} = -0.1$ V to 2 V, $V_{OUT} = V_{CC}/2$ $T_{min} < T_{op} < T_{max}$ $V_{icm} = -0.1$ V to 4.6 V, $V_{OUT} = V_{CC}/2$ $T_{min} < T_{op} < T_{max}$	61 59	82		dB
A_{vd}	Large signal voltage gain	$R_L = 2$ kΩ, $V_{out} = 0.3$ V to 4.2 V $T_{min} < T_{op} < T_{max}$ $R_L = 10$ kΩ, $V_{out} = 0.2$ V to 4.3 V $T_{min} < T_{op} < T_{max}$	100 90	108		
V_{OH}	High level output voltage	$R_L = 2$ kΩ to $V_{CC}/2$ $T_{min} < T_{op} < T_{max}$ $R_L = 10$ kΩ to $V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		50	80 100	mV from V_{CC+}
V_{OL}	Low level output voltage	$R_L = 2$ kΩ to $V_{CC}/2$ $T_{min} < T_{op} < T_{max}$ $R_L = 10$ kΩ to $V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		10	16 20	
I_{out}	I_{sink}	$V_{out} = 4.5$ V $T_{min} < T_{op} < T_{max}$	16 13	21		mA
	I_{source}	$V_{out} = 0$ V $T_{min} < T_{op} < T_{max}$	16 13	21		
I_{CC}	Supply current (per amplifier)	No load, $V_{out} = V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		2.9	3.4 3.5	MHz
GBP	Gain bandwidth product	$R_L = 10$ kΩ, $C_L = 20$ pF, $G = 20$ dB		9		
F_U	Unity gain frequency			9.3		Degrees
ϕ_m	Phase margin	$R_L = 10$ kΩ, $C_L = 20$ pF		60		
G_m	Gain margin			6.7		

Table 4. Electrical characteristics at $V_{CC+} = +4.5$ V with $V_{CC-} = 0$ V, $V_{icm} = V_{CC}/2$, $T_{amb} = 25$ °C, and $R_L = 10$ kΩ connected to $V_{CC}/2$ (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
SR+	Positive slew rate	$Av = +1$, $V_{out} = 0.5$ to 4.0 V Measured between 10 % to 90 %		14.7		V/μs
SR-	Negative slew rate	$Av = +1$, $V_{out} = 4.0$ to 0.5 V Measured between 90 % to 10 %		17.2		
e_n	Equivalent input noise voltage	$f = 10$ kHz $f = 100$ kHz		17.9 12.9		nV/√Hz
$\int e_n$	Low-frequency peak-to-peak input noise	Bandwidth: $f = 0.1$ to 10 Hz		8.1		μV _{pp}
THD+N	Total harmonic distortion + noise	$f = 1$ kHz, $Av = +1$, $R_L = 10$ kΩ, $V_{out} = 2$ V _{rms}		0.002		%
Shutdown characteristics (TSX920 and TSX923 only)						
I_{CC_shdn}	Supply current in shutdown mode (per amplifier)	$SHDN = V_{CC-}$ $T_{min} < T_{op} < T_{max}$		7	15 20	μA
t_{on}	Amplifier turn-on time			9		μs
t_{off}	Amplifier turn-off time			0.7		μs

Table 5. Electrical characteristics at $V_{CC+} = +10$ V with $V_{CC-} = 0$ V, $V_{icm} = V_{CC}/2$, $T_{amb} = 25$ °C, and $R_L = 10$ kΩ connected to $V_{CC}/2$ (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{io}	Input offset voltage	$T_{min} < T_{op} < T_{max}$			4 5	mV
$\Delta V_{io}/\Delta T$	Input offset voltage drift			2	10	µV/°C
I_{ib}	Input bias current	$V_{out} = V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		10	100 200	pA
I_{io}	Input offset current	$V_{out} = V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		10	100 200	
R_{IN}	Input resistance			1		TΩ
C_{IN}	Input capacitance			8		pF
CMRR	Common mode rejection ratio 20 log ($\Delta V_{ic}/\Delta V_{io}$)	$V_{icm} = -0.1$ V to 7 V, $V_{OUT} = V_{CC}/2$ $T_{min} < T_{op} < T_{max}$	72 70	85		dB
		$V_{icm} = -0.1$ V to 10.1 V, $V_{OUT} = V_{CC}/2$ $T_{min} < T_{op} < T_{max}$	64 62	75		
A_{vd}	Large signal voltage gain	$R_L = 2$ kΩ, $V_{out} = 0.3$ V to 9.7 V $T_{min} < T_{op} < T_{max}$	100 90	107		mV
		$R_L = 10$ kΩ, $V_{out} = 0.2$ V to 9.8 V $T_{min} < T_{op} < T_{max}$	100 90	117		
V_{OH}	High level output voltage	$R_L = 2$ kΩ to $V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		94	110 130	mV from V_{CC+}
		$R_L = 10$ kΩ to $V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		31	40 50	
V_{OL}	Low level output voltage	$R_L = 2$ kΩ to $V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		80	110 130	mV
		$R_L = 10$ kΩ to $V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		14	40 50	
I_{out}	I_{sink}	$V_{out} = 10$ V $T_{min} < T_{op} < T_{max}$	50 42	55		mA
	I_{source}	$V_{out} = 0$ V $T_{min} < T_{op} < T_{max}$	75 70	82		
I_{cc}	Supply current (per amplifier)	No load, $V_{out} = V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		3.1	3.6 3.6	
GBP	Gain bandwidth product	$R_L = 10$ kΩ, $C_L = 20$ pF, $G = 20$ dB		10		MHz
F_U	Unity gain frequency			11.2		
ϕ_m	Phase margin	$R_L = 10$ kΩ, $C_L = 20$ pF		56		Degrees
G_m	Gain margin			6		dB

Table 5. Electrical characteristics at $V_{CC+} = +10$ V with $V_{CC-} = 0$ V, $V_{icm} = V_{CC}/2$, $T_{amb} = 25$ °C, and $R_L = 10$ kΩ connected to $V_{CC}/2$ (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
SR+	Positive slew rate	$Av = +1$, $V_{out} = 0.5$ to 9.5 V Measured between 10 % to 90 %		17.7		$V/\mu s$
SR-	Negative slew rate	$Av = +1$, $V_{out} = 9.5$ to 0.5 V Measured between 90 % to 10 %		19.6		
e_n	Equivalent input noise voltage	$f = 10$ kHz $f = 100$ kHz		16.8 12		nV/\sqrt{Hz}
$\int e_n$	Low-frequency peak-to-peak input noise	Bandwidth: $f = 0.1$ to 10 Hz		8.64		μV_{pp}
THD+N	Total harmonic distortion + noise	$f = 1$ kHz, $Av = +1$, $R_L = 10$ kΩ, $V_{out} = 2$ V _{rms}		0.0006		%
Shutdown characteristics (TSX920 and TSX923 only)						
I_{CC_shdn}	Supply current in shutdown mode (per amplifier)	$SHDN = V_{CC-}$ $T_{min} < T_{op} < T_{max}$		7	15 20	μA
t_{on}	Amplifier turn-on time			2.4		μs
t_{off}	Amplifier turn-off time			0.35		μs

Table 6. Electrical characteristics at $V_{CC+} = +16$ V with $V_{CC-} = 0$ V, $V_{icm} = V_{CC}/2$, $T_{amb} = 25$ °C, and $R_L = 10$ kΩ connected to $V_{CC}/2$ (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{io}	Input offset voltage	$T_{min} < T_{op} < T_{max}$			4 5	mV
$\Delta V_{io}/\Delta T$	Input offset voltage drift			2	10	µV/°C
I_{ib}	Input bias current	$V_{out} = V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		10	100 200	pA
I_{io}	Input offset current	$V_{out} = V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		10	100 200	
R_{IN}	Input resistance			1		TΩ
C_{IN}	Input capacitance			8		pF
CMRR	Common mode rejection ratio 20 log $(\Delta V_{ic}/\Delta V_{io})$	$V_{icm} = -0.1$ V to 13 V, $V_{OUT}=V_{CC}/2$ $T_{min} < T_{op} < T_{max}$	73 71	85		dB
		$V_{icm} = -0.1$ V to 16.1 V, $V_{OUT} = V_{CC}/2$ $T_{min} < T_{op} < T_{max}$	67 65	76		
SVRR	Supply voltage rejection ratio	$V_{cc} = 4.5$ V to 16 V $T_{min} < T_{op} < T_{max}$	73 71	85		
A_{vd}	Large signal voltage gain	$R_L = 2$ kΩ $V_{out} = 0.3$ V to 15.7 V $T_{min} < T_{op} < T_{max}$	100 90	105		
		$R_L = 10$ kΩ $V_{out} = 0.2$ V to 15.8 V $T_{min} < T_{op} < T_{max}$	100 90	113		
V_{OH}	High level output voltage	$R_L = 2$ kΩ to $V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		150	200 230	mV from V_{CC+}
		$R_L = 10$ kΩ to $V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		43	50 70	
V_{OL}	Low level output voltage	$R_L = 2$ kΩ to $V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		140	200 230	mV
		$R_L = 10$ kΩ to $V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		30	50 70	
I_{out}	I_{sink}	$V_{out} = 16$ V $T_{min} < T_{op} < T_{max}$	45 40	50		mA
	I_{source}	$V_{out} = 0$ V $T_{min} < T_{op} < T_{max}$	65 60	74		
I_{CC}	Supply current (per amplifier)	No load, $V_{out} = V_{CC}/2$ $T_{min} < T_{op} < T_{max}$		2.8	3.4 3.4	
GBP	Gain bandwidth product	$R_L = 10$ kΩ, $C_L = 20$ pF, $G = 20$ dB		10		MHz
F_U	Unity gain frequency	$R_L = 10$ kΩ, $C_L = 20$ pF		12		
ϕ_m	Phase margin			55		Degrees
G_m	Gain margin			5.9		dB

Table 6. Electrical characteristics at $V_{CC+} = +16$ V with $V_{CC-} = 0$ V, $V_{icm} = V_{CC}/2$, $T_{amb} = 25$ °C, and $R_L = 10$ kΩ connected to $V_{CC}/2$ (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
SR+	Positive slew rate	Av = +1, $V_{out} = 0.5$ to 15.5 V Measured between 10 % to 90 %		16.2		V/μs
SR-	Negative slew rate	Av = +1, $V_{out} = 15.5$ to 0.5 V Measured between 90 % to 10 %		17.2		
e_n	Equivalent input noise voltage	f = 10 kHz f = 100 kHz		16.5 11.8		nV/√Hz
$\int e_n$	Low-frequency peak-to-peak input noise	Bandwidth: f = 0.1 to 10 Hz		8.58		μV _{pp}
THD+N	Total harmonic distortion + Noise	f = 1 kHz, Av = +1, $R_L = 10$ kΩ, $V_{out} = 4V_{rms}$		0.0003		%
t_S	Settling time	Gain = +1, 100 mV input voltage 0.1 % of final value 1 % of final value		245 178		ns

Shutdown characteristics (TSX920 and TSX923 only)

I_{CC_shdn}	Supply current in shutdown mode (per amplifier)	$\overline{SHDN} = V_{CC-}$ $T_{min} < T_{op} < T_{max}$		7	15 20	μA
t_{on}	Amplifier turn-on time			1.5		μs
t_{off}	Amplifier turn-off time			0.2		μs

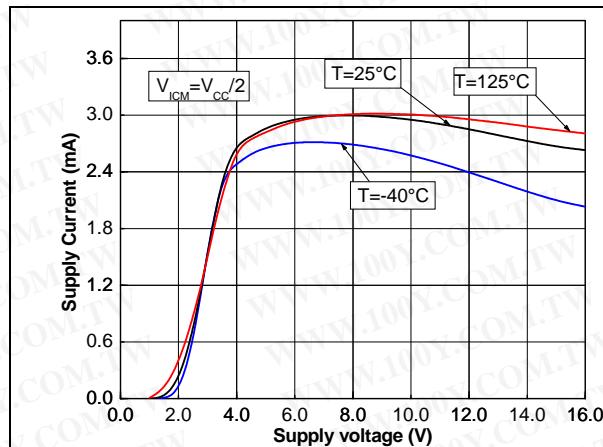
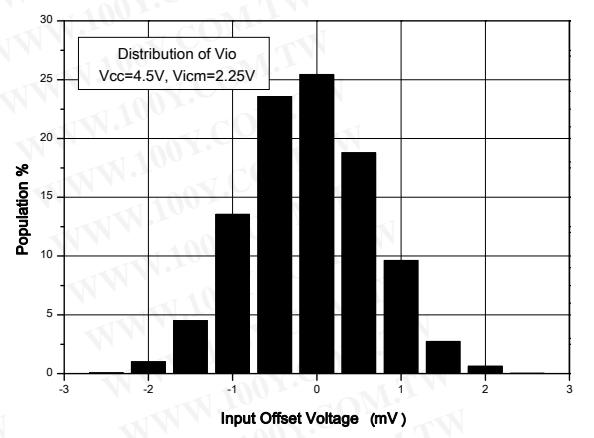
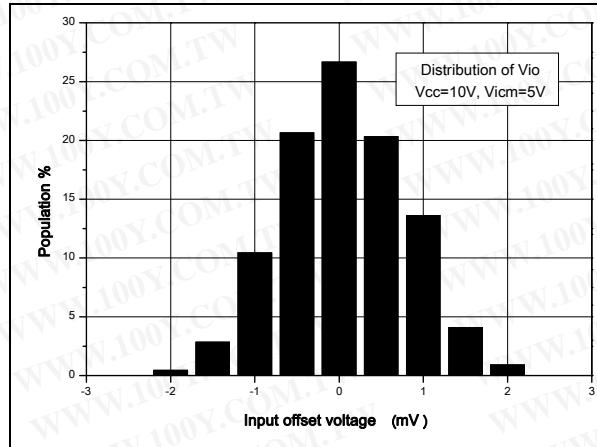
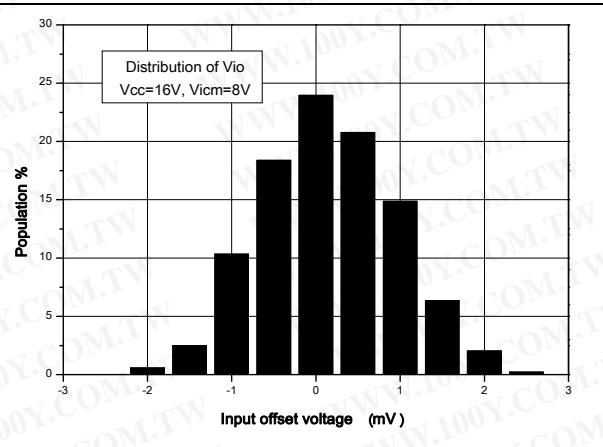
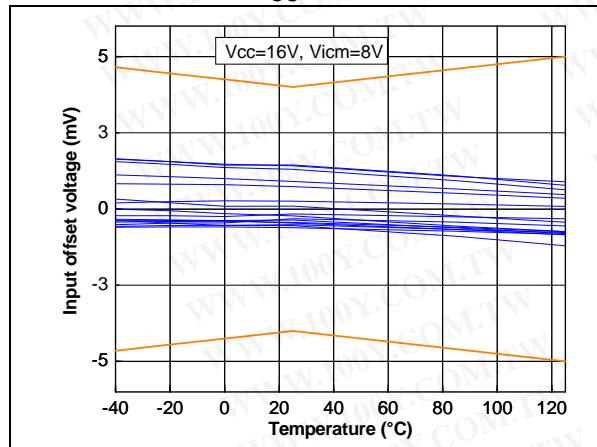
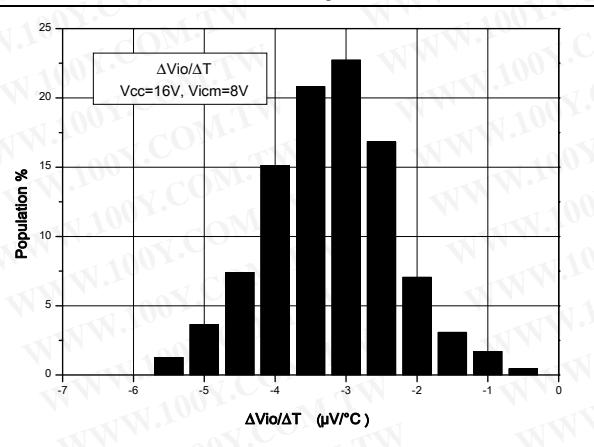
Figure 2. Supply current vs. supply voltage**Figure 3. Distribution of input offset voltage at $V_{CC} = 4.5\text{ V}$** **Figure 4. Distribution of input offset voltage at $V_{CC} = 10\text{ V}$** **Figure 5. Distribution of input offset voltage at $V_{CC} = 16\text{ V}$** **Figure 6. Input offset voltage vs. temperature at $V_{CC} = 16\text{ V}$** **Figure 7. Distribution of input offset voltage drift over temperature**

Figure 8. Input offset voltage vs. common mode voltage at $V_{CC} = 4\text{ V}$ **Figure 9. Input offset voltage vs. common mode voltage at $V_{CC} = 16\text{ V}$**

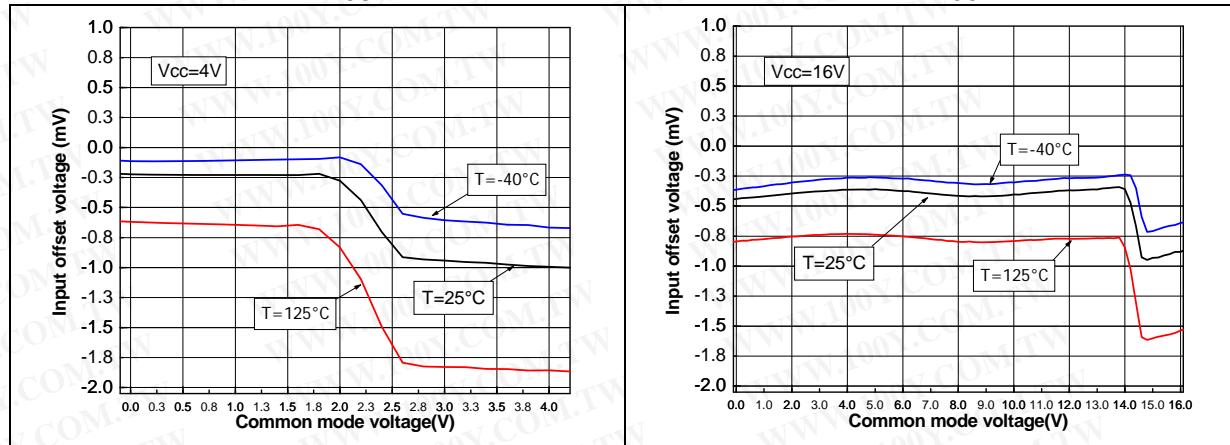


Figure 10. Output current vs. output voltage at $V_{CC} = 4\text{ V}$

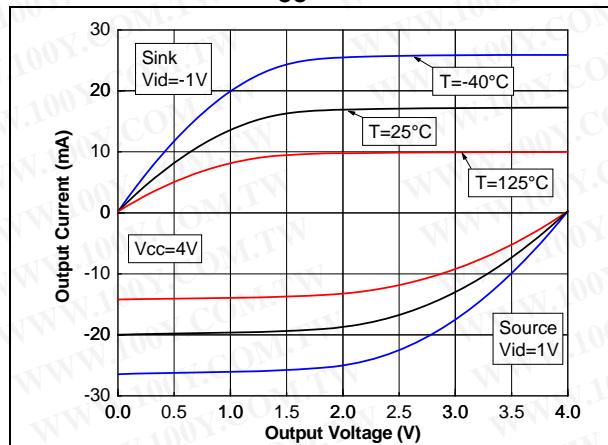


Figure 11. Output current vs. output voltage at $V_{CC} = 10\text{ V}$

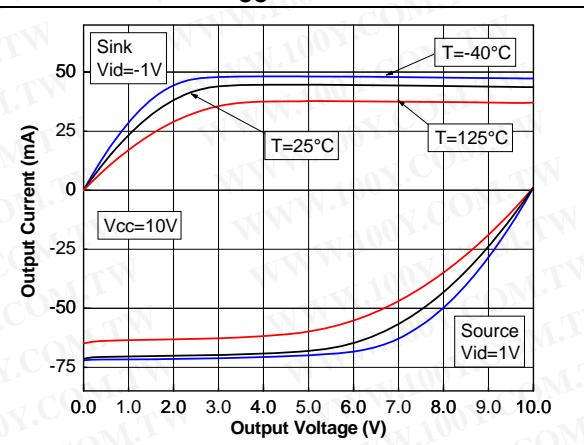


Figure 12. Output current vs. output voltage at $V_{CC} = 16\text{ V}$

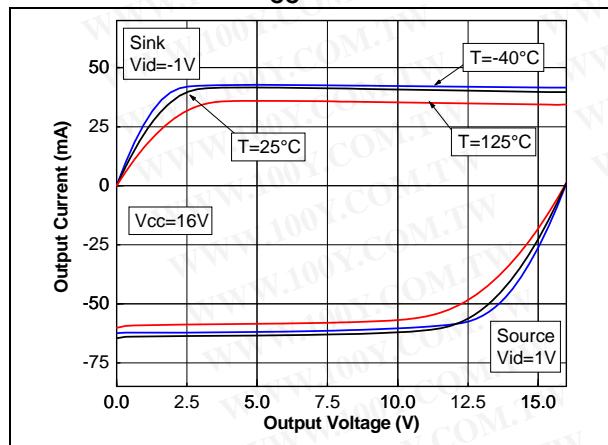


Figure 13. Output rail linearity

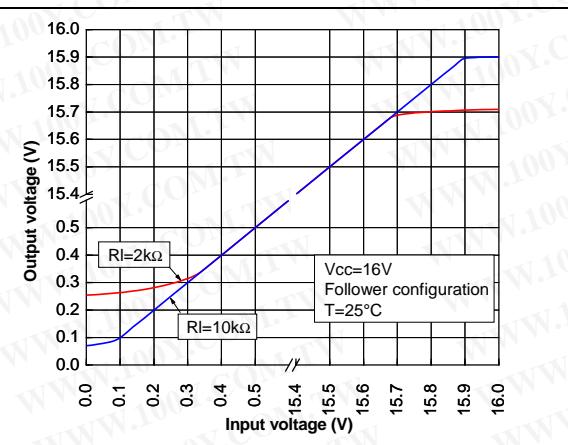


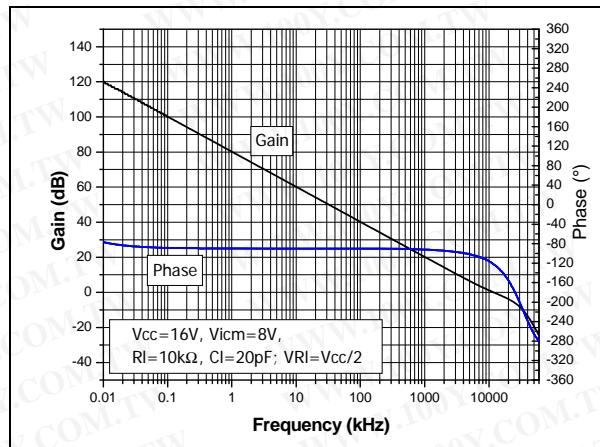
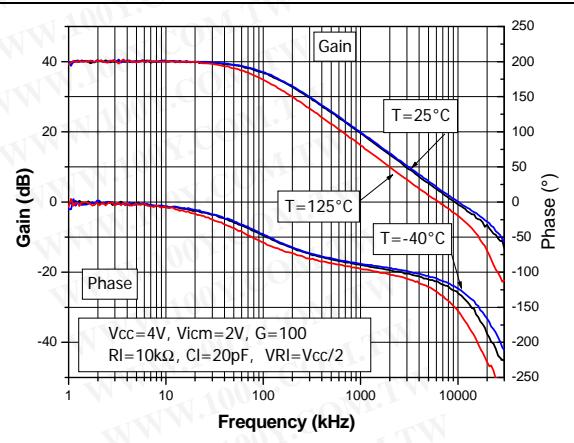
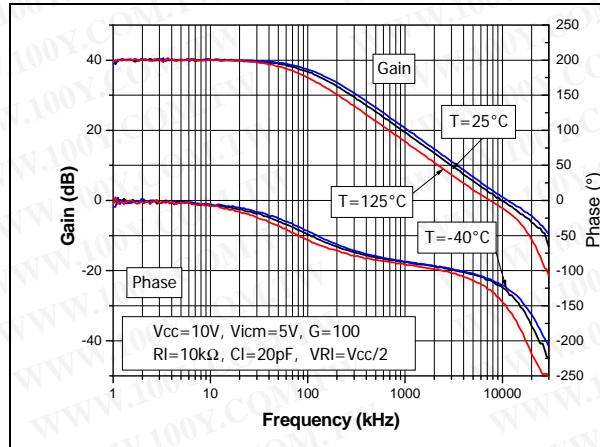
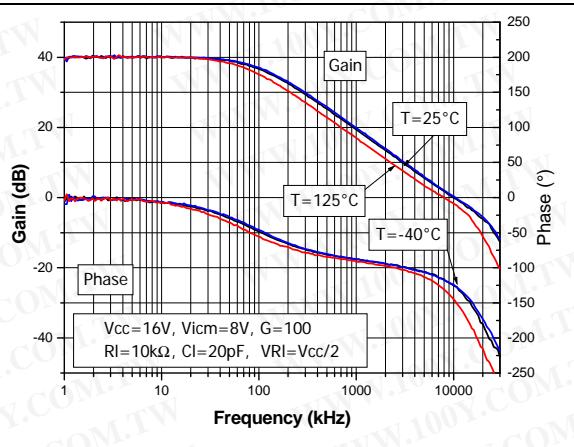
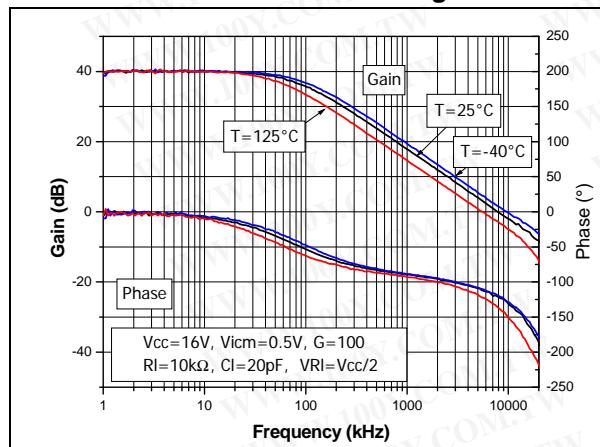
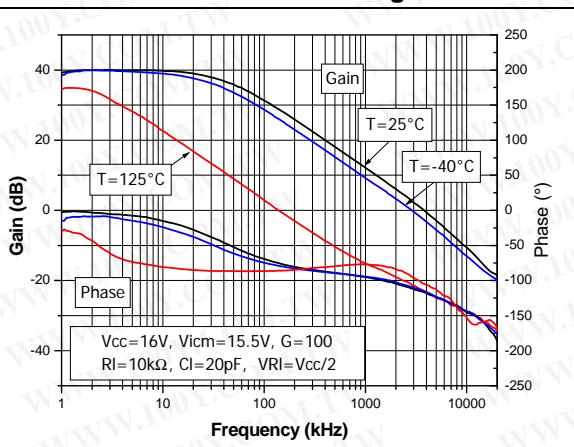
Figure 14. Open loop gain vs. frequency**Figure 15. Bode diagram vs. temperature for $V_{CC} = 4V$** **Figure 16. Bode diagram vs. temperature for $V_{CC} = 10V$** **Figure 17. Bode diagram vs. temperature for $V_{CC} = 16V$** **Figure 18. Bode diagram at $V_{CC} = 16V$ with low common mode voltage****Figure 19. Bode diagram at $V_{CC} = 16V$ with high common mode voltage**

Figure 20. Bode diagram at $V_{CC} = 16$ V and $R_L = 10 \text{ k}\Omega$, $C_L = 47 \text{ pF}$

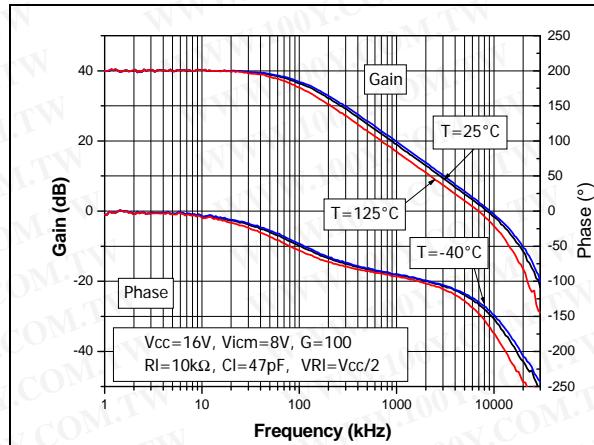


Figure 21. Bode diagram at $V_{CC} = 16$ V and $R_L = 10 \text{ k}\Omega$, $C_L = 120 \text{ pF}$

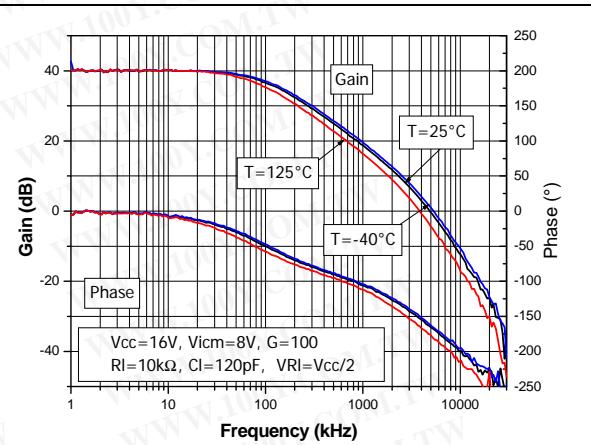


Figure 22. Bode diagram at $V_{CC} = 16$ V and $R_L = 2.2 \text{ k}\Omega$, $C_L = 20 \text{ pF}$

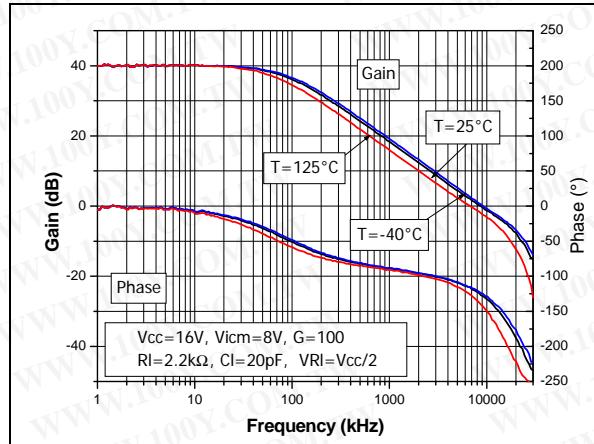


Figure 23. Slew rate vs. supply voltage and temperature

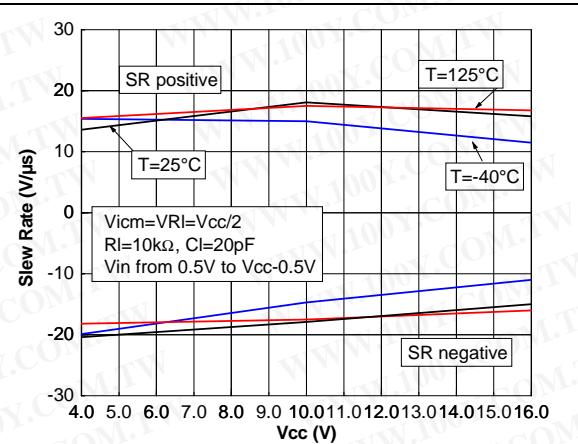


Figure 24. Overshoot vs. capacitive load without feedback capacitor

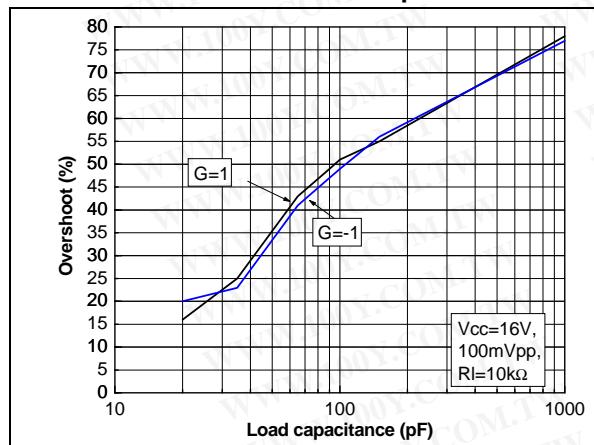


Figure 25. Closed loop gain vs. frequency with different gain resistors

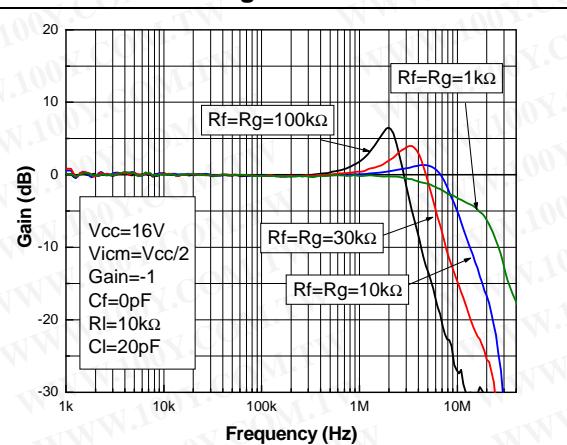


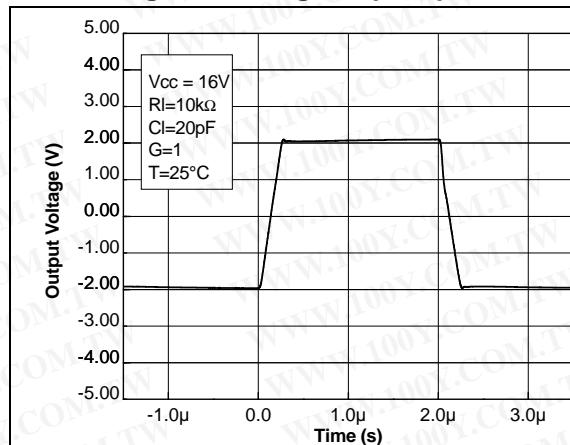
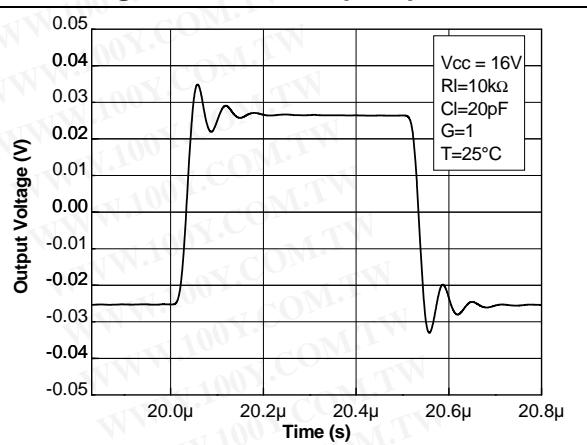
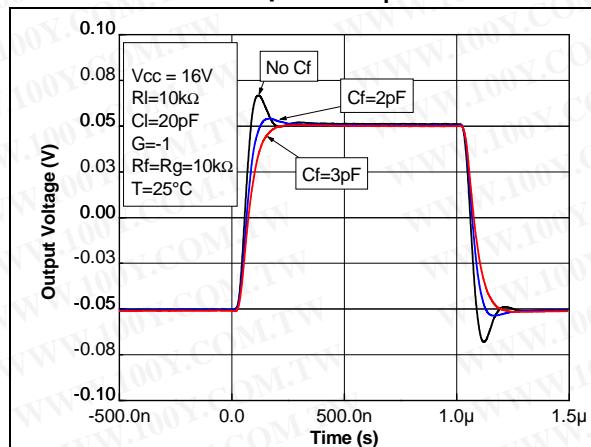
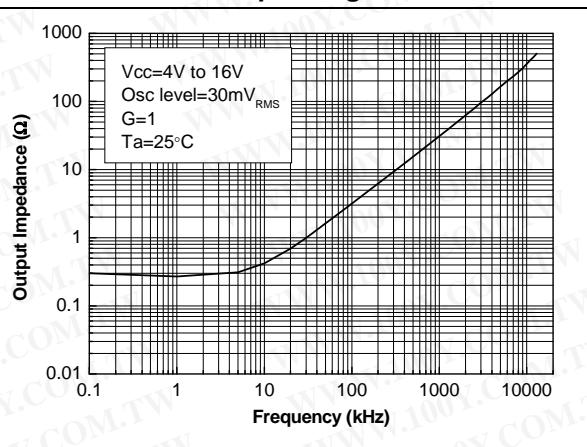
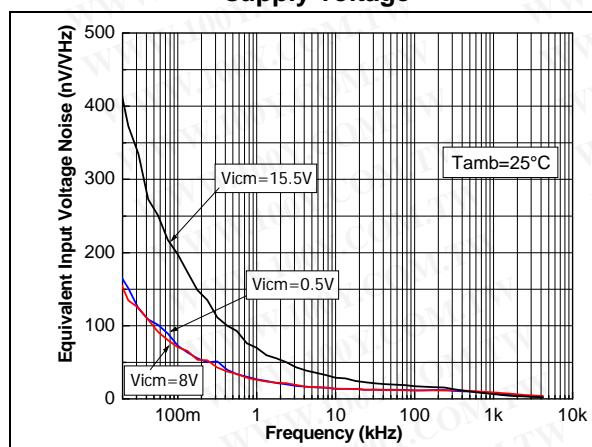
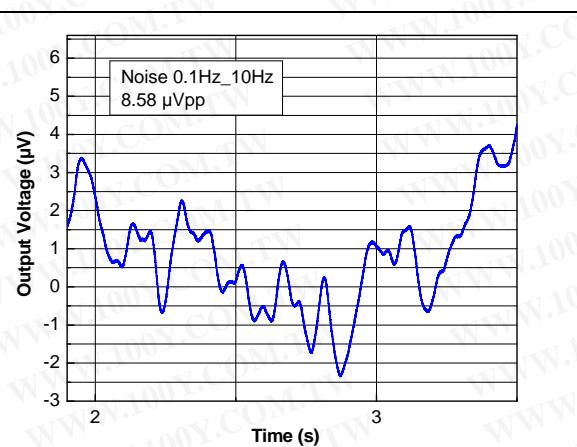
Figure 26. Large step response**Figure 27. Small step response****Figure 28. Small step response with feedback capacitor C_f****Figure 29. Output impedance vs. frequency in closed loop configuration****Figure 30. Noise vs. frequency with 16 V supply voltage****Figure 31. 0.1 to 10 Hz noise**

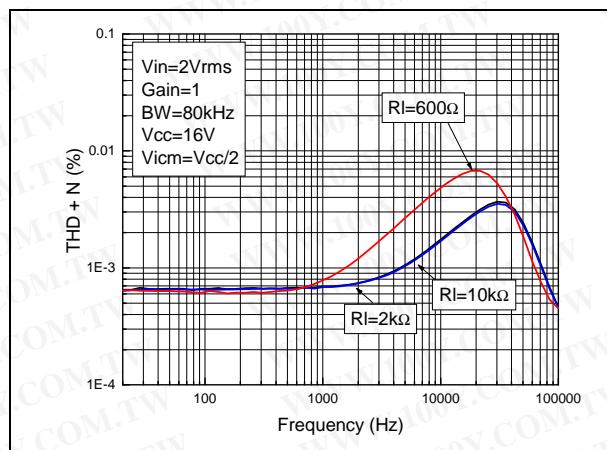
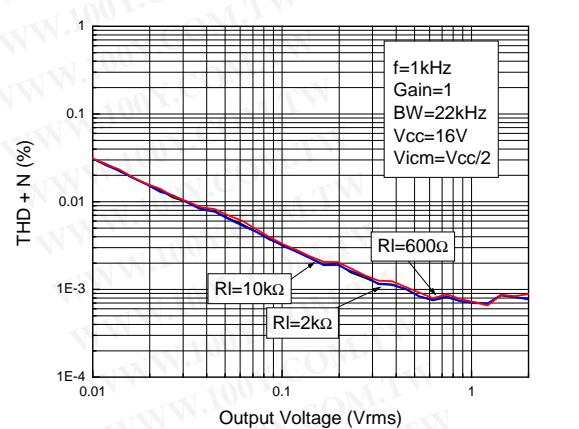
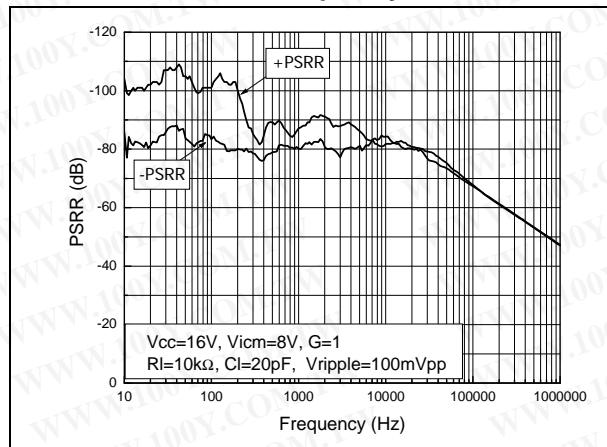
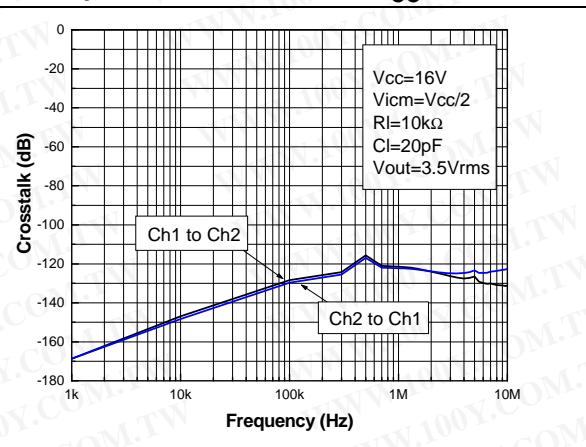
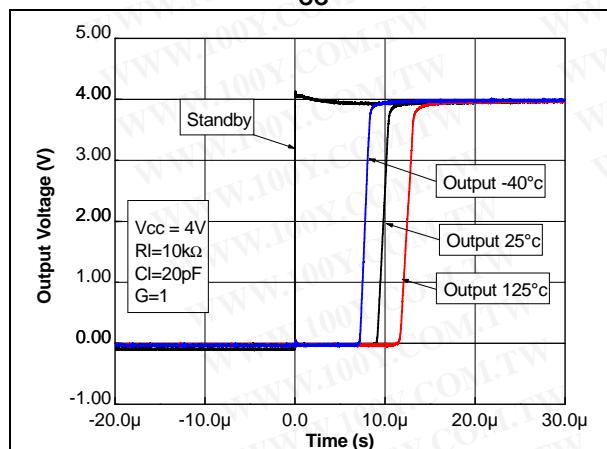
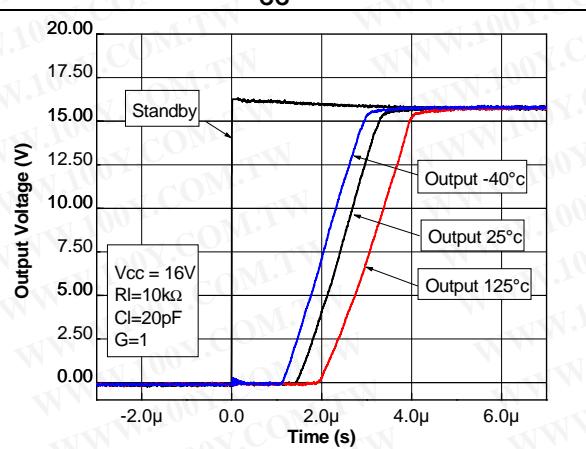
Figure 32. THD+N vs. frequency at $V_{CC} = 16$ VFigure 33. THD+N vs. output voltage at $V_{CC} = 16$ V

Figure 34. Power supply rejection ratio (PSRR) vs. frequency

Figure 35. Crosstalk vs. frequency between operators on TSX922 at $V_{CC} = 16$ VFigure 36. Startup time after standby released for $V_{CC} = 4$ VFigure 37. Startup time after standby released for $V_{CC} = 16$ V

4 Application information

4.1 Operating voltages

The TSX92x operational amplifiers can operate from 4 V to 16 V. The parameters are fully specified at 4.5 V, 10 V, and 16 V power supplies. However, parameters are very stable in the full V_{CC} range. Additionally, main specifications are guaranteed in the extended temperature range from -40 to +125 °C.

4.2 Rail-to-rail input

The TSX92x series is designed with two complementary PMOS and NMOS input differential pairs. The device has a rail-to-rail input and the input common mode range is extended from $(V_{CC-}) - 0.1$ V to $(V_{CC+}) + 0.1$ V. However, the performance of this device is clearly optimized for the PMOS differential pairs (which means from $(V_{CC-}) - 0.1$ V to $(V_{CC+}) - 2$ V).

Beyond $(V_{CC+}) - 2$ V, the operational amplifier is still functional but with downgraded performances (see [Figure 19](#)). Performances are still suitable for a large number of applications requiring the rail-to-rail input feature.

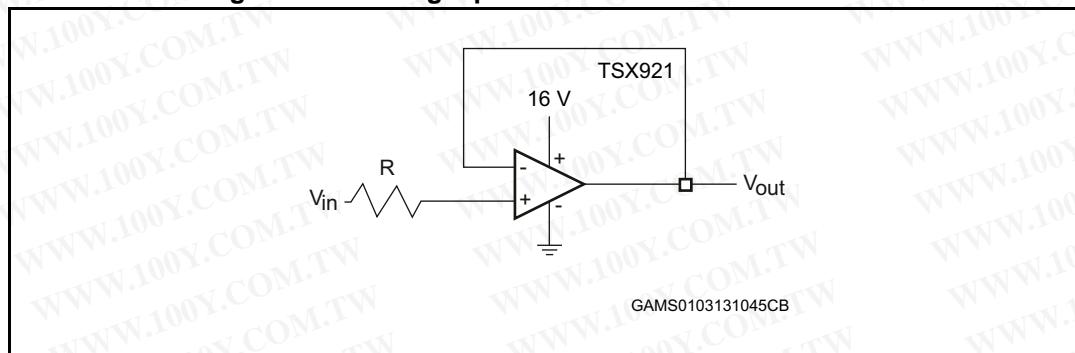
The TSX92x operational amplifiers are designed to prevent phase reversal.

4.3 Input pin voltage range

The TSX92x operational amplifiers have internal ESD diode protections on the inputs. These diodes are connected between the input and each supply rail to protect MOSFETs inputs from electrostatic discharges.

Thus, if the input pin voltage exceeds the power supply by 0.5 V, the ESD diodes become conductive and excessive current could flow through them. To prevent any permanent damage, this current must be limited to 10 mA. This can be done by adding a resistor in series with the input pin ([Figure 38](#)). The resistor value has to be calculated for a 10 mA current limitation on the input pins.

Figure 38. Limiting input current with a series resistor



4.4 Capacitive load

Driving a large capacitive load can cause stability issues. Increasing the load capacitance produces gain peaking in the frequency response, with overshooting and ringing in the step response. It is usually considered that with a gain peaking higher than 2.3 dB the op-amp might become unstable. Generally, the unity gain configuration is the worst configuration for stability and the ability to drive large capacitive loads. [Figure 39](#) shows the serial resistor (R_{iso}) that must be added to the output, to make the system stable.

Figure 39. Stability criteria with a serial resistor

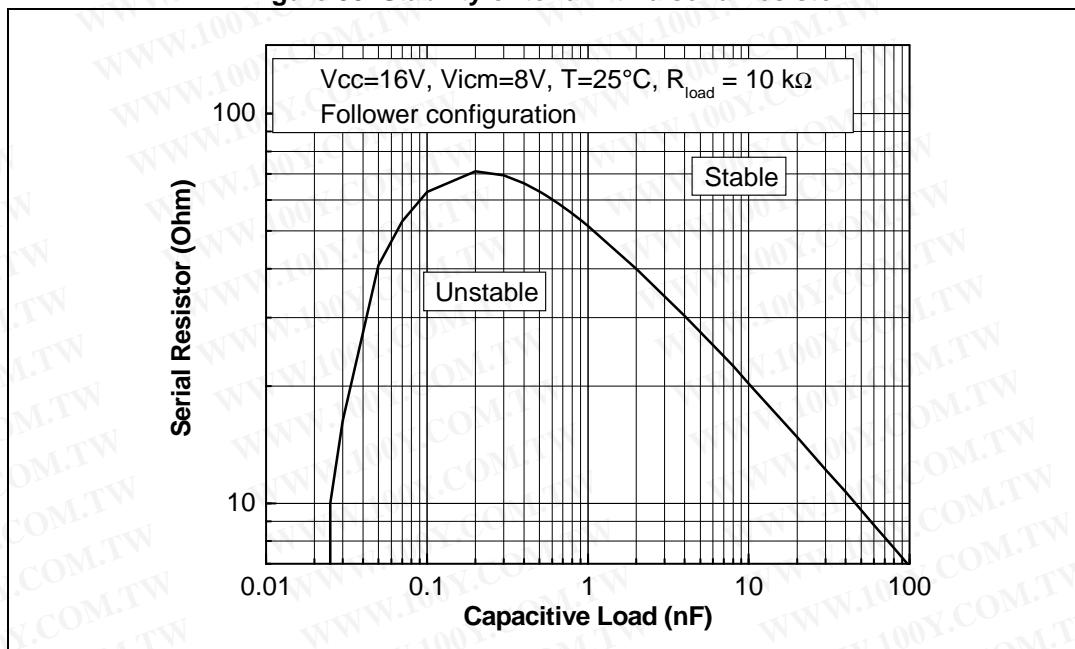
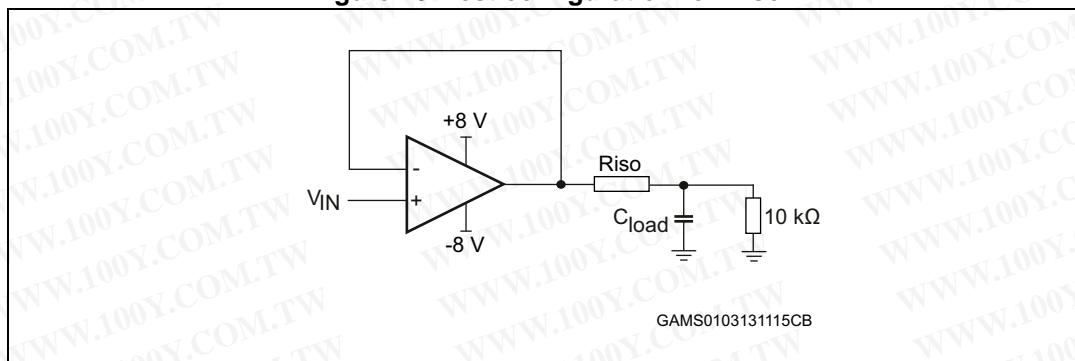


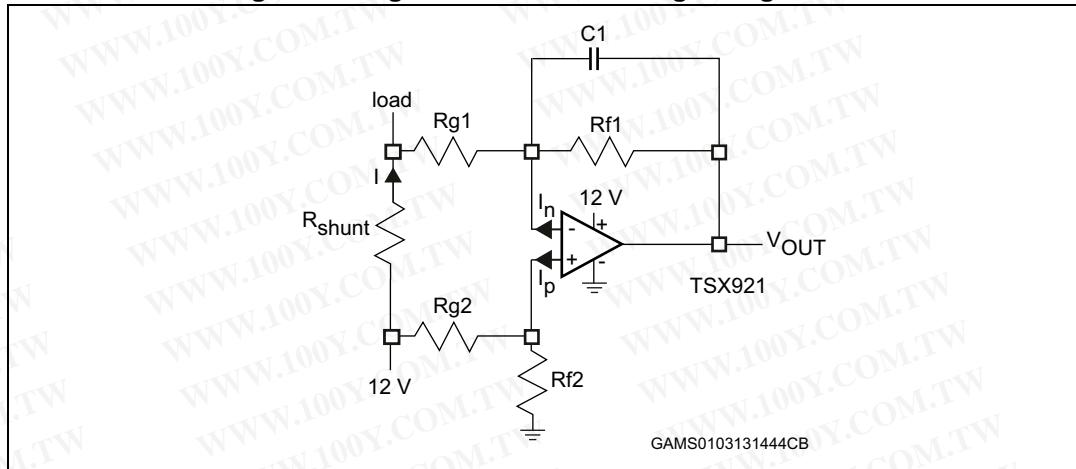
Figure 40. Test configuration for Riso



4.5 High side current sensing

TSX92x rail to rail input devices can be used to measure a small differential voltage on a high side shunt resistor and translate it into a ground referenced output voltage. The gain is fixed by external resistance.

Figure 41. High side current sensing configuration



V_{OUT} can be expressed as shown in [Equation 1](#).

Equation 1

$$V_{out} = R_{shunt} \times I \left(1 - \frac{R_{g2}}{R_{g2} + R_{f2}} \right) \left(1 + \frac{R_{f1}}{R_{g1}} \right) + I_p \left(\frac{R_{g2} R_{f2}}{R_{g2} + R_{f2}} \right) \times \left(1 + \frac{R_{f1}}{R_{g1}} \right) - I_n \times R_{f1} - V_{io} \left(1 + \frac{R_{f1}}{R_{g1}} \right)$$

Assuming that $R_{f2} = R_{f1} = R_f$ and $R_{g2} = R_{g1} = R_g$, [Equation 1](#) can be simplified as [Equation 2](#).

Equation 2

$$V_{out} = R_{shunt} \times I \left(\frac{R_f}{R_g} \right) - V_{io} \left(1 + \frac{R_f}{R_g} \right) + R_f \times I_{io}$$

With the TSX92x operational amplifiers, the high side current measurement must be made by respecting the common mode voltage of the amplifier: $(V_{CC-}) - 0.1\text{ V}$ to $(V_{CC+}) + 0.1\text{ V}$. If the application requires a higher common voltage please refer to the TSC high side current sensing family.

4.6 High speed photodiode

The TSX92x series is an excellent choice for current to voltage (I-V) conversions. Due to the CMOS technology, the input bias currents are extremely low. Moreover, the low noise and high unity-gain bandwidth of the TSX92x operational amplifiers make them particularly suitable for high-speed photodiode preamplifier applications.

The photodiode is considered as a capacitive current source. The input capacitance, C_{IN} , includes the parasitic input Common mode capacitance, C_{CM} (3pF), and the input differential mode capacitance, C_{DIFF} (8pF). C_{IN} acts in parallel with the intrinsic capacitance of the photodiode, C_D . At higher frequencies, the capacitors affect the circuit response. The output capacitance of a current sensor has a strong effect on the stability of the op-amp feedback loop.

C_F stabilizes the gain and limits the transimpedance bandwidth. To ensure good stability and to obtain good noise performance, C_F can be set as shown in [Equation 3](#).

Equation 3

$$C_F > \sqrt{\frac{C_{IN} + C_D}{2 \cdot \pi \cdot R_F \cdot F_{GBP}}} - C_{SMR}$$

where,

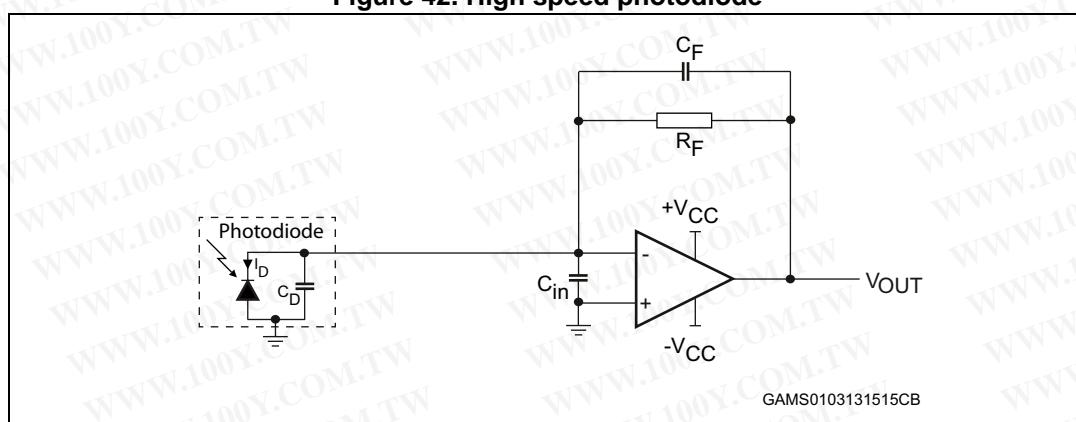
- $C_{IN} = C_{CM} + C_{DIFF} = 11 \text{ pF}$
- C_{DIFF} is the differential input capacitance: 8 pF typical
- C_{CM} is the Common mode input capacitance: 3 pF typical
- C_D is the intrinsic capacitance of the photodiode
- C_{SMR} is the parasitic capacitance of the surface mount R_F resistor: 0.2 pF typical
- F_{GBP} is the gain bandwidth product: 10 MHz at 16 V

R_F fixes the gain as shown in [Equation 4](#).

Equation 4

$$V_{OUT} = R_F \times I_D$$

Figure 42. High speed photodiode



5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com.
ECOPACK® is an ST trademark.

5.1 SOT23-5 package mechanical data

Figure 43. SOT23-5 package mechanical drawing

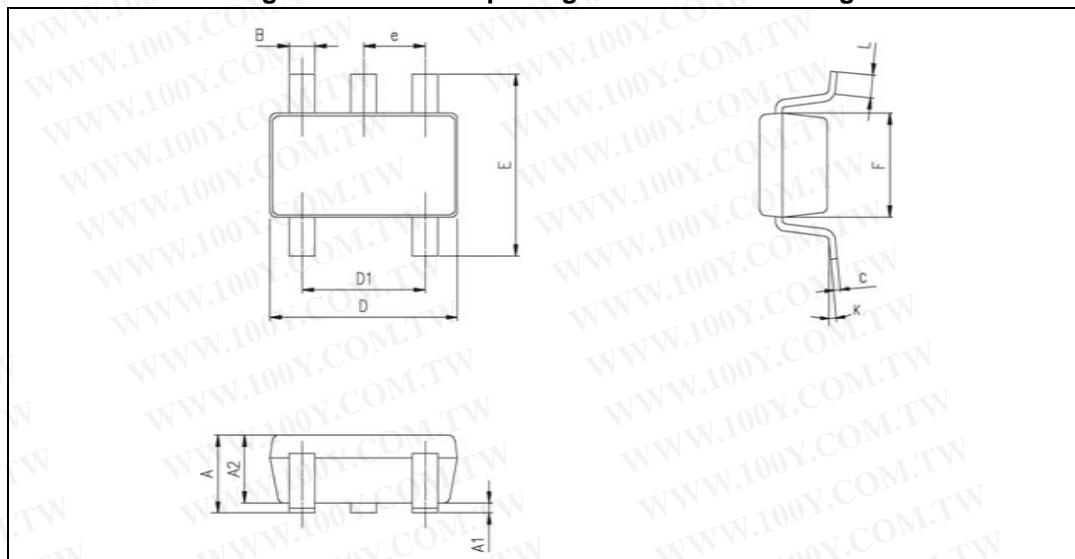


Table 7. SOT23-5 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.90	1.20	1.45	0.035	0.047	0.057
A1			0.15			0.006
A2	0.90	1.05	1.30	0.035	0.041	0.051
B	0.35	0.40	0.50	0.013	0.015	0.019
C	0.09	0.15	0.20	0.003	0.006	0.008
D	2.80	2.90	3.00	0.110	0.114	0.118
D1		1.90			0.075	
e		0.95			0.037	
E	2.60	2.80	3.00	0.102	0.110	0.118
F	1.50	1.60	1.75	0.059	0.063	0.069
L	0.10	0.35	0.60	0.004	0.013	0.023
K	0 degrees		10 degrees			

5.2 SOT23-6 package mechanical data

Figure 44. SOT23-6 package mechanical drawing

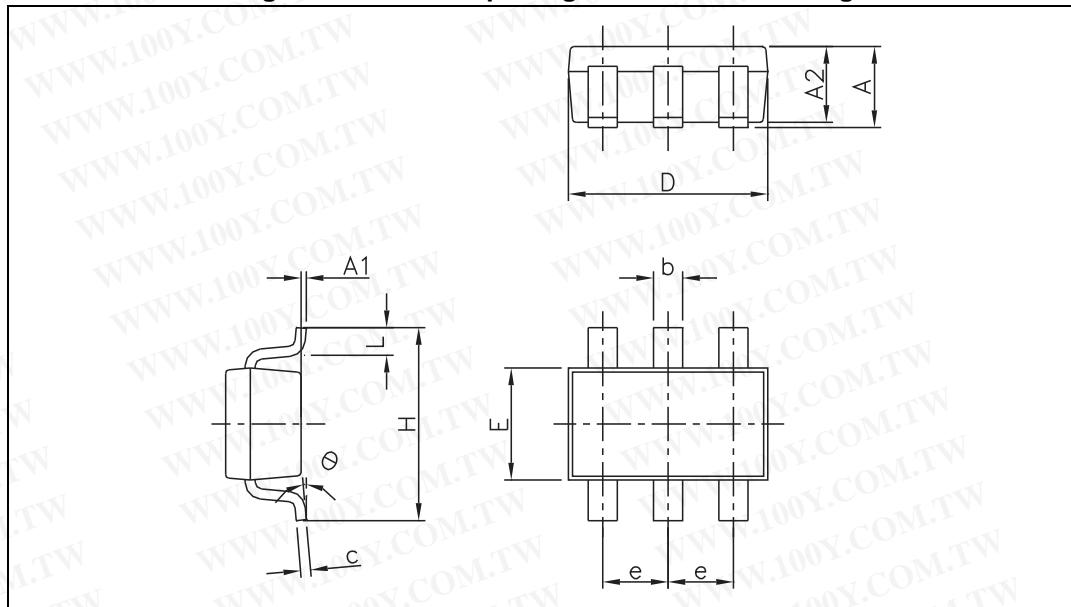


Table 8. SOT23-6 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.90		1.45	0.035		0.057
A1			0.10			0.004
A2	0.90		1.30	0.035		0.051
b	0.35		0.50	0.013		0.019
c	0.09		0.20	0.003		0.008
D	2.80		3.05	0.110		0.120
E	1.50		1.75	0.060		0.069
e		0.95			0.037	
H	2.60		3.00	0.102		0.118
L	0.10		0.60	0.004		0.024
Θ	0 °		10 °	0 °		10 °

5.3 MiniSO8 package information

Figure 45. MiniSO8 package mechanical drawing

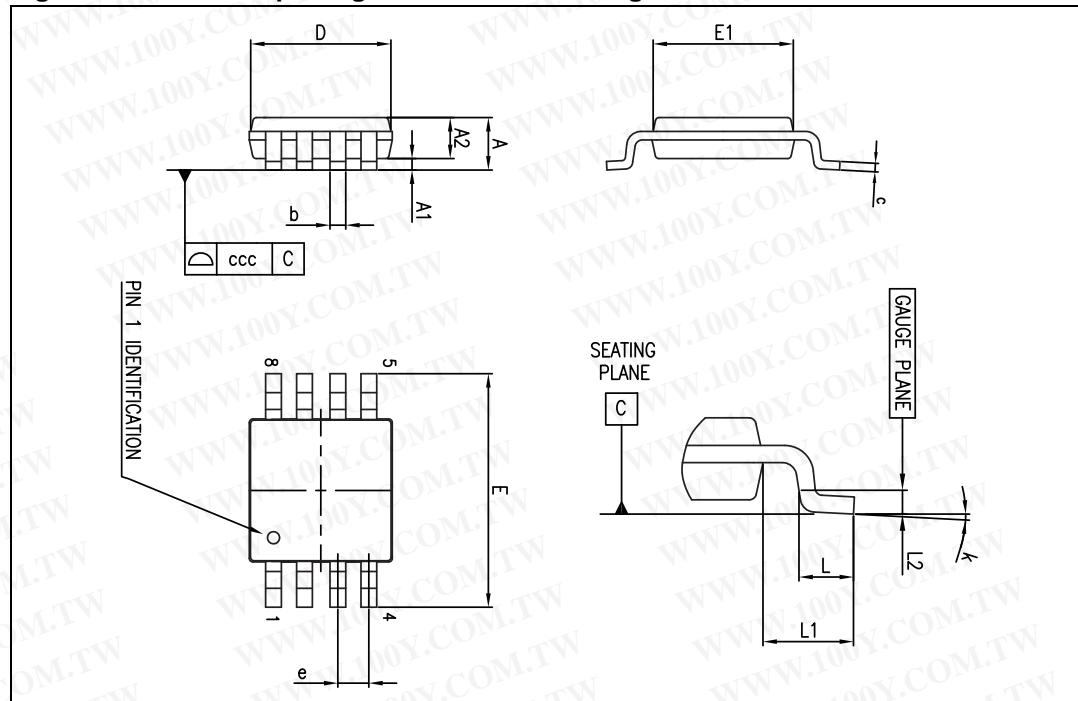


Table 9. MiniSO8 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.1			0.043
A1	0		0.15	0		0.006
A2	0.75	0.85	0.95	0.030	0.033	0.037
b	0.22		0.40	0.009		0.016
c	0.08		0.23	0.003		0.009
D	2.80	3.00	3.20	0.11	0.118	0.126
E	4.65	4.90	5.15	0.183	0.193	0.203
E1	2.80	3.00	3.10	0.11	0.118	0.122
e		0.65			0.026	
L	0.40	0.60	0.80	0.016	0.024	0.031
L1		0.95			0.037	
L2		0.25			0.010	
k	0 °		8 °	0 °		8 °
ccc			0.10			0.004

5.4 SO8 package information

Figure 46. SO8 package mechanical drawing

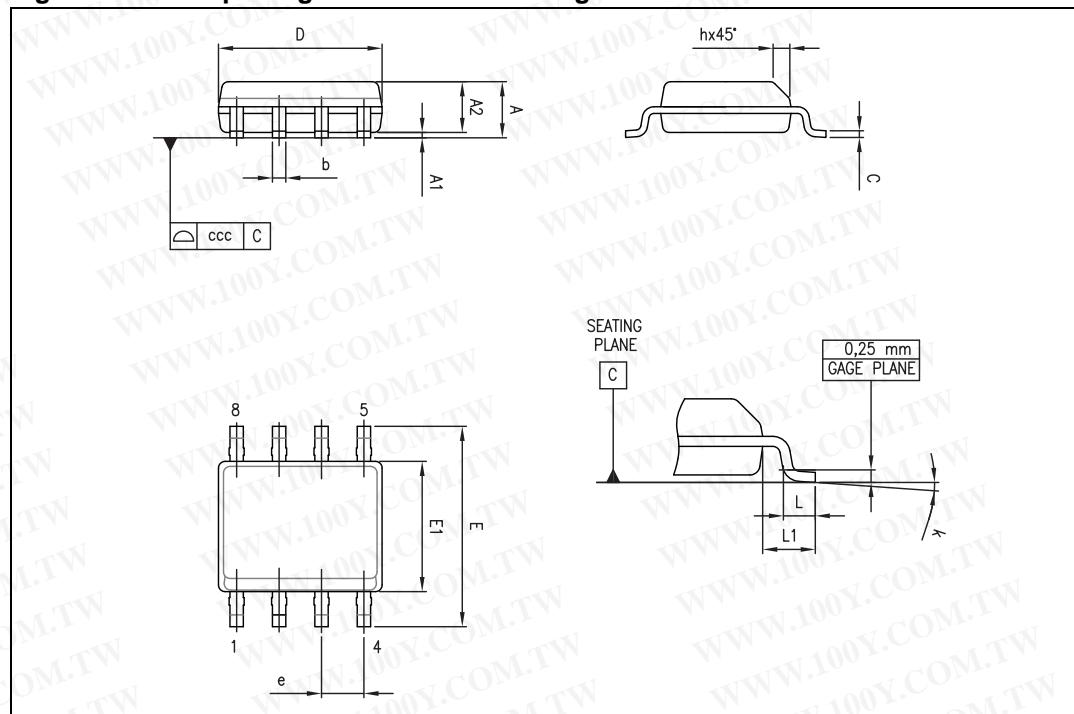


Table 10. SO8 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
c	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
E	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
e		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
L1		1.04			0.040	
k	0		8 °	1 °		8 °
ccc			0.10			0.004

5.5 DFN8 2x2 package information

Figure 47. DFN8 2x2 package mechanical drawing

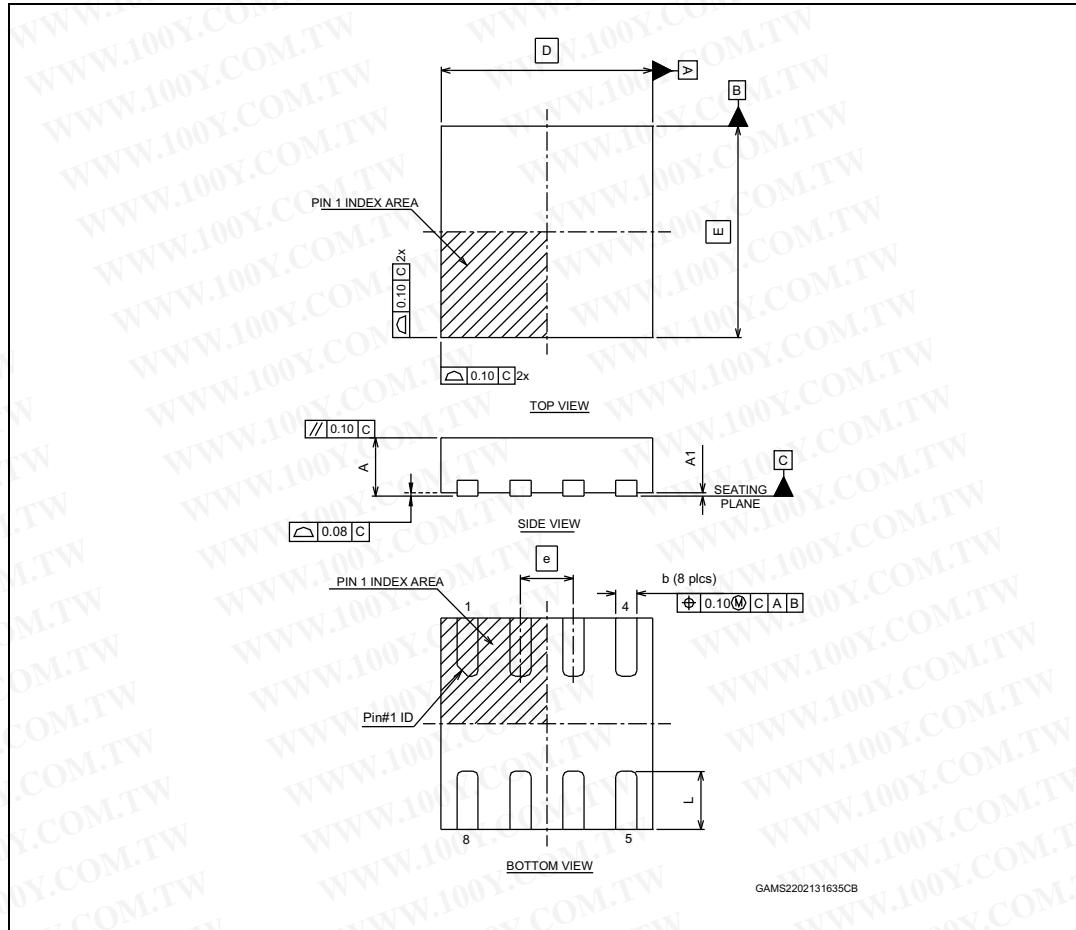


Table 11. DFN8 2x2 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.70	0.75	0.80	0.028	0.030	0.031
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.15	0.20	0.25	0.006	0.008	0.010
D		2.00			0.079	
E		2.00			0.079	
e		0.50			0.020	
L	0.045	0.55	0.65	0.018	0.022	0.026
N	8			8		

5.6 MiniSO10 package information

Figure 48. MiniSO10 package mechanical drawing

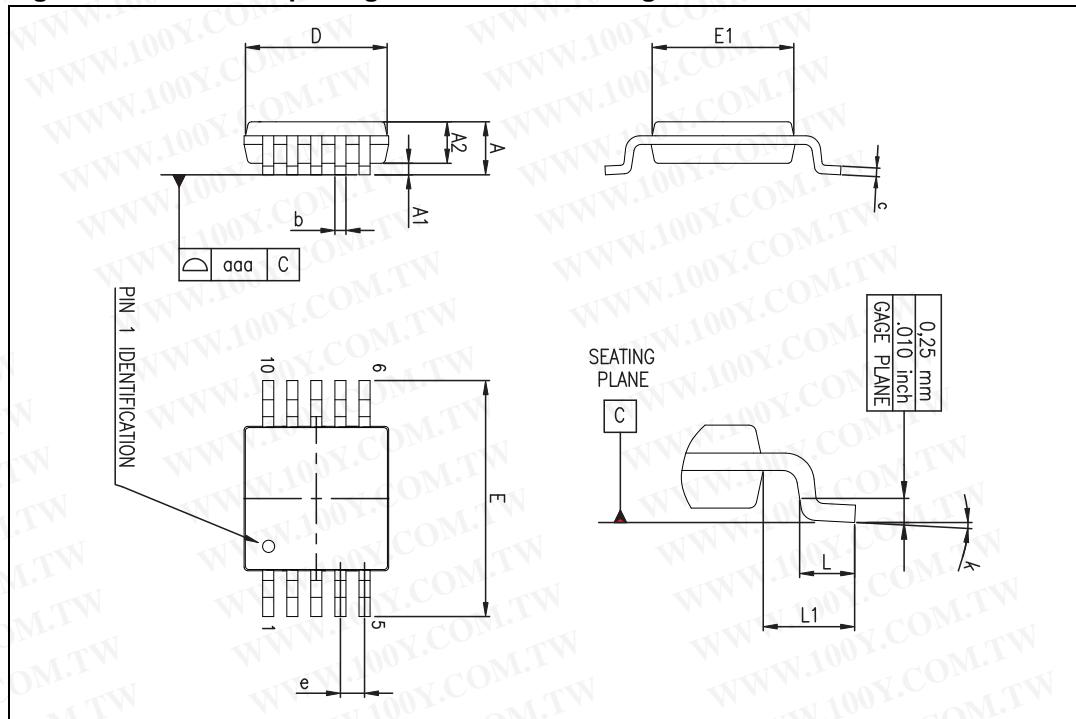


Table 12. MiniSO10 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.10			0.043
A1	0.05	0.10	0.15	0.002	0.004	0.006
A2	0.78	0.86	0.94	0.031	0.034	0.037
b	0.25	0.33	0.40	0.010	0.013	0.016
c	0.15	0.23	0.30	0.006	0.009	0.012
D	2.90	3.00	3.10	0.114	0.118	0.122
E	4.75	4.90	5.05	0.187	0.193	0.199
E1	2.90	3.00	3.10	0.114	0.118	0.122
e		0.50			0.020	
L	0.40	0.55	0.70	0.016	0.022	0.028
L1		0.95			0.037	
k	0 °	3 °	6 °	0 °	3 °	6 °
aaa			0.10			0.004

6 Ordering information

Table 13. Order codes

Order code	Temperature range	Package	Packing	Marking
TSX920ILT	-40 °C to +125 °C	SOT23-6	Tape and reel	K304
TSX921ILT		SOT23-5		K305
TSX921IYL ⁽¹⁾		SO8		TSX922I
TSX922IDT		MiniSO8		SX922IY
TSX922IYDT ⁽¹⁾		DFN8 2x2		K305
TSX922IST		MiniSO10		K26
TSX922IQ2T				K305
TSX923IST				

1. Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent.

7 Revision history

Table 14. Document revision history

Date	Revision	Changes
12-Apr-2013	1	Initial release
27-Jun-2013	2	Added TSX920, TSX922, TSX923 devices. Added packages for TSX920, TSX922, and TSX923. Added shutdown characteristics in Table 4 , Table 5 , and Table 6 . Added Figure 35 , Figure 36 , and Figure 37 . Updated Table 13 for new order codes.

勝特力材料 886-3-5753170
胜特力电子(上海) 86-21-34970699
胜特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

ST PRODUCTS ARE NOT AUTHORIZED FOR USE IN WEAPONS. NOR ARE ST PRODUCTS DESIGNED OR AUTHORIZED FOR USE IN: (A) SAFETY CRITICAL APPLICATIONS SUCH AS LIFE SUPPORTING, ACTIVE IMPLANTED DEVICES OR SYSTEMS WITH PRODUCT FUNCTIONAL SAFETY REQUIREMENTS; (B) AERONAUTIC APPLICATIONS; (C) AUTOMOTIVE APPLICATIONS OR ENVIRONMENTS, AND/OR (D) AEROSPACE APPLICATIONS OR ENVIRONMENTS. WHERE ST PRODUCTS ARE NOT DESIGNED FOR SUCH USE, THE PURCHASER SHALL USE PRODUCTS AT PURCHASER'S SOLE RISK, EVEN IF ST HAS BEEN INFORMED IN WRITING OF SUCH USAGE, UNLESS A PRODUCT IS EXPRESSLY DESIGNATED BY ST AS BEING INTENDED FOR "AUTOMOTIVE, AUTOMOTIVE SAFETY OR MEDICAL" INDUSTRY DOMAINS ACCORDING TO ST PRODUCT DESIGN SPECIFICATIONS. PRODUCTS FORMALLY ESCC, QML OR JAN QUALIFIED ARE DEEMED SUITABLE FOR USE IN AEROSPACE BY THE CORRESPONDING GOVERNMENTAL AGENCY.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2013 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -
Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

